NSN 5961-01-180-4082

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-180-4082 **Inclosure Material:** Metal **Overall Length:** Between 0.300 inches and 0.405 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud Thready Qty Per Inch (tpi): 32 **Thread Size:** 0.169 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 working peak reverse voltage **Current Rating Per Characteristic:** 400.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air and 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli Fiig:

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